

KSE45H Series

General Purpose Power Switching Applications

- Low Collector-Emitter Saturation Voltage: V_{CE}(sat) = -1V (MAX)@-8A
- Fast Switching Speeds
- Complement to KSE44H



1.Base 2.Collector 3.Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage : KSE45H 1,2	- 30	V
	: KSE45H 4,5	- 45	V
	: KSE45H 7,8	- 60	V
	: KSE45H 10,11	- 80	V
V _{EBO}	Emitter- Base Voltage	- 5	V
I _C	Collector Current (DC)	- 10	Α
I _{CP}	*Collector Current (Pulse)	- 20	Α
P _C	Collector Dissipation (T _C =25°C)	50	W
P _C	Collector Dissipation (T _a =25°C)	1.67	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CES}	Collector Cut-off Current	$V_{CE} = Rated, V_{CEO}, V_{EB} = 0$			-10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			-100	μΑ
h _{FE}	*DC Current Gain : KSE45H 1, 4, 7 10 : KSE45H 2, 5, 8,11	V _{CE} = - 1V, I _C = - 2A	35 60			
V _{CE} (sat)	*Collector-Emitter Saturation Voltage : KSE45H 1, 4, 7 10 : KSE45H 2, 5, 8,11	I _C = -8A, I _B = -0.8A I _C = -8A, I _B = -0.4A			-1 -1	V V
V _{BE} (sat)	*Base-Emitter Saturation Voltage	I _C = -8A, I _B = -0.8A			-1.5	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -10V, I_{C} = -0.5A$		40		MHz
C _{ob}	Output Capacitance	V _{CB} = - 10V, f = 1MHz		230		pF
t _{ON}	Turn ON Time	$V_{CC} = 20V, I_{C} = -5A$		135		ns
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = -0.5A$		500		ns
t _F	Fall Time			100		ns

^{*} Pulse test: PW≤300μs, Duty cycle≤2%

Typical Characteristics

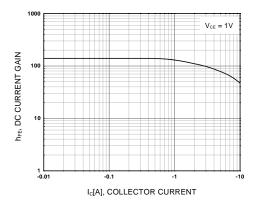


Figure 1. DC current Gain

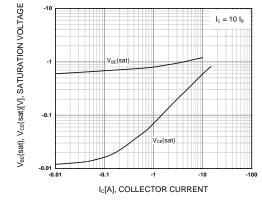


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

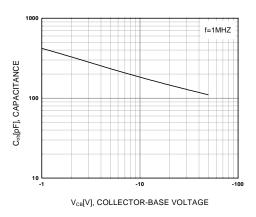


Figure 3. Collector Output Capacitance

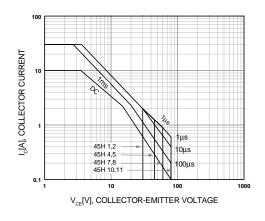


Figure 4. Safe Operating Area

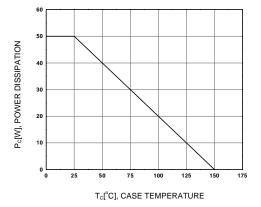
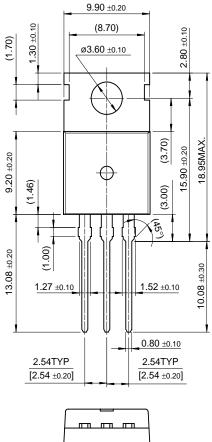


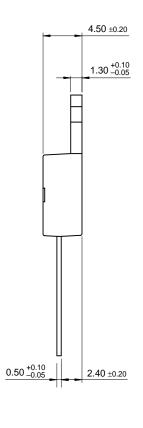
Figure 5. Power Derating

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Package Demensions

TO-220





10.00 ±0.20

Dimensions in Millimeters

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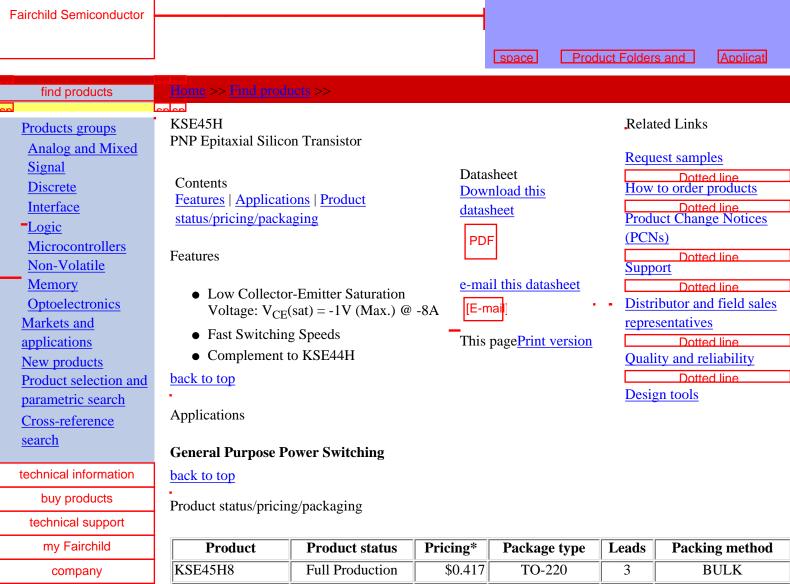
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Product	Product status	Pricing*	Package type	Leads	Packing method
KSE45H8	Full Production	\$0.417	TO-220	3	BULK
KSE45H8TU	Full Production	\$0.417	TO-220	3	RAIL
KSE45H11TU	Full Production	\$0.417	TO-220	3	RAIL
KSE45H11	Full Production	\$0.417	TO-220	3	BULK

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